Bulletin PD-2.093 revB 10/04

International
IOR Rectifier

40HFL, 70HFL, 85HFL SERIES

FAST RECOVERY DIODES

Stud Version

case style
DO-203AB (DO-5)

Major Ratings and Characteristics

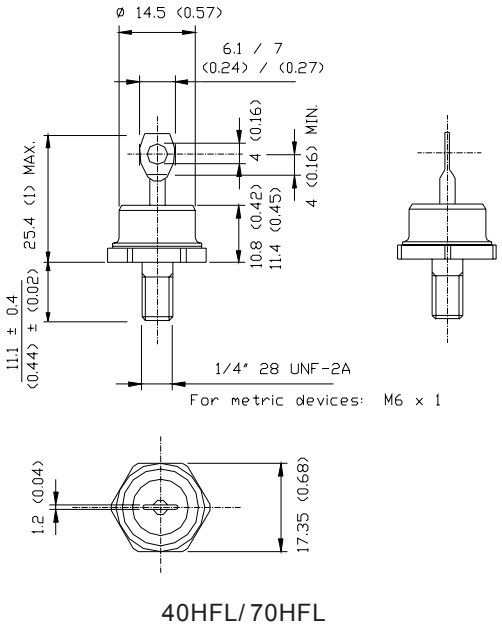
Parameters		40HFL	70HFL	85HFL	Units
$I_{F(AV)}$		40	70	85	A
@ Max Tc		75	75	75	A
I_{FSM}	@50Hz	400	700	1100	A
	@60Hz	420	730	1151	A
I^2t	@50Hz	800	2450	6050	A^2s
	@60Hz	730	2240	5523	A^2s
$I^2\sqrt{t}$		11300	34650	85560	$I^2\sqrt{s}$
V_{RRM}	range	100 to 1000			V
t_{rr}	range	see table			ns
T_J	range	- 40 to 125			°C

Description

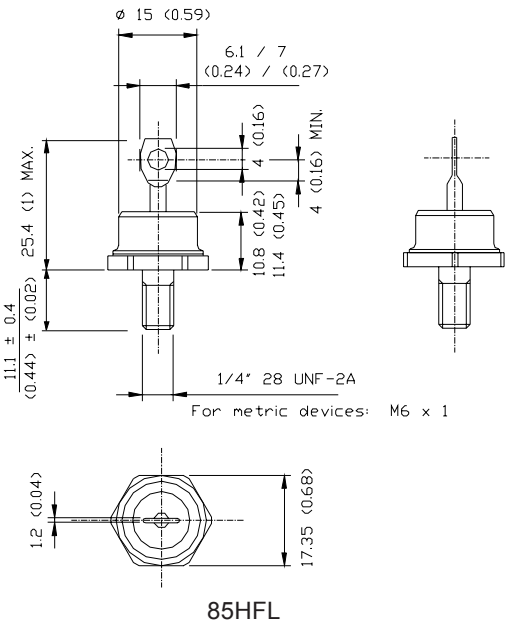
This range of fast recovery diodes is designed for applications in DC power supplies, inverters, converters, choppers, ultrasonic systems and for use as a free wheeling diode.

Features

- Short reverse recovery time
- Low stored charge
- Wide current range
- Excellent surge capabilities
- Stud cathode and stud anode versions
- Types up to 1000V_{RRM}



40HFL/70HFL



85HFL

ELECTRICAL SPECIFICATIONS

Reverse voltage ratings

Part number ①	V_{RRM}, Maximum peak repetitive reverse voltage T_J = −40 to 125°C V	V_{RSM}, Maximum peak non-repetitive reverse voltage T_J = 25 to 125°C V	I_{FM} Maximum peak reverse current at rated V_{RRM}: T_J = 25°C mA	T_J = 125°C mA
40HFL10S02, 40HFL10S05, 40HFL10S10	100	150	0.1	10
40HFL20S02, 40HFL20S05, 40HFL20S10	200	300	0.1	10
40HFL40S02, 40HFL40S05, 40HFL40S10	400	500	0.1	10
40HFL60S02, 40HFL60S05, 40HFL60S10	600	700	0.1	10
40HFL80S05, 40HFL80S10	800	900	0.1	10
40HFL100S05, 40HFL100S10	1000	1100	0.1	10
70HFL10S02, 70HFL10S05, 70HFL10S10	100	150	0.1	15
70HFL20S02, 70HFL20S05, 70HFL20S10	200	300	0.1	15
70HFL40S02, 70HFL40S05, 70HFL40S10	400	500	0.1	15
70HFL60S02, 70HFL60S05, 70HFL60S10	600	700	0.1	15
70HFL80S05, 70HFL80S10	800	900	0.1	15
70HFL100S05, 70HFL100S10	1000	1100	0.1	15
85HFL10S02, 85HFL10S05, 85HFL10S10	100	150	0.1	20
85HFL20S02, 85HFL20S05, 85HFL20S10	200	300	0.1	20
85HFL40S02, 85HFL40S05, 85HFL40S10	400	500	0.1	20
85HFL60S02, 85HFL60S05, 85HFL60S10	600	700	0.1	20
85HFL80S05, 85HFL80S10	800	900	0.1	20
85HFL100S05, 85HFL100S10	1000	1100	0.1	20

①Types listed are cathode case, for anode case add "R" to code, i.e. 40HFLR20S02, 85HFLR100S05 etc.

Reverse recovery characteristics

		40HFL...			70HFL...			85HFL...			Units	Conditions
		S02	S05	S10	S02	S05	S10	S02	S05	S10		
t_{rr}	Typical reverse recovery time	70	180	350	60	150	290	50	120	270	ns	T_J = 25°C, I_F = 1A to V_R = 30V, $-dI_{F/dt}$ = 100A/µs
		200	500	1000	200	500	1000	200	500	1000	ns	T_J = 25°C, $-dI_{F/dt}$ = 25A/µs, I_{FM} = πx rated $I_{F(AV)}$
Q_{RR}	Typical reverse recovered charge	160	750	3100	90	500	1600	70	340	1350	nC	T_J = 25°C, I_F = 1A to V_R = 30V, $-dI_{F/dt}$ = 100A/µs
		240	1300	6000	240	1300	6000	240	1300	6000	nC	T_J = 25°C, $-dI_{/dt}$ = 25A/µs, I_{FM} = πx rated $I_{F(AV)}$

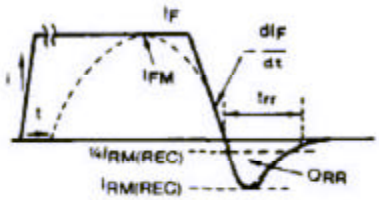
Forward conduction

		40HFL	70HFL	85HFL	Units	Conditions	
$I_{F(AV)}$	Maximum average forward current	40	70	85	A	180°C conduction, half sine wave, max. T_C = 75°C	
$I_{F(RMS)}$	Maximum RMS forward current	63	110	134	A		
I_{FRM}	Maximum peak repetitive forward current	220	380	470	A	Sinusoidal half wave, 30° conduction	
I_{FSM}	Maximum peak, one cycle non-repetitive forward current	400	700	1100	A	t = 10ms	Sinusoidal half-wave 100% V_{RRM} reapplied, initial T_J = T_J max
		420	730	1151	A	t = 8.3ms	
		475	830	1308	A	t = 10ms	Sinusoidal half-wave no voltage reapplied, initial T_J = T_J max
		500	870	1369	A	t = 8.3ms	
I^2t	Maximum I^2t for fusing	800	2450	6050	A^2s	t = 10ms	100% V_{RRM} reapplied initial T_J = T_J max
		730	2240	5523	A^2s	t = 8.3ms	
		1130	3460	8556	A^2s	t = 10ms	No voltage reapplied initial T_J = T_J max
		1030	3160	7810	A^2s	t = 8.3ms	
$I^2\sqrt{t}$	Maximum $I^2\sqrt{t}$ for fusing ①	11 300	34 650	85 560	$A^2\sqrt{s}$	t = 0.1 to 10ms, no voltage reapplied	
$V_{F(TO)}$	Maximum value of threshold voltage	1.081	1.085	1.128	V	T_J = 125°C	
r_F	Maximum value of forward slope resistance	6.33	3.40	2.11	mΩ		
V_{FM}	Maximum peak forward voltage	1.95	1.85	1.75	V	T_J = 25°C, I_{FM} = πx $I_{F(AV)}$	

① I^2t for time t_x = $I^2\sqrt{t}$ · $\sqrt{t_x}$.

THERMAL AND MECHANICAL SPECIFICATIONS

			40HFL...	70HFL...	85HFL...	Units	Conditions
T_J	Junction operating temperature range			−40 to 125		°C	
T_{stg}	Storage temperature range			−40 to 150		°C	
R_{thJC}	Maximum internal thermal resistance, junction to case		0.60	0.36	0.30	K/W	DC operation
R_{thCS}	Maximum thermal resistance, case to heatsink			0.25		K/W	Mounting surface, smooth, flat and greased
T	Mounting torque 10%	to nut		20 (27)		lbf•in	Lubricated threads (non-lubricated threads)
				0.23 (0.29)		kgf•m	
				2.2 (2.7)		N•m	
		to device		22		lbf•in	
				0.25		kgf•m	
				2.5		N•m	
wt	Approximate weight			25 (0.88)		g (oz)	
	Outline			DO-203AB (DO-5)			JEDEC



I_F, I_{FM} = Peak forward current prior to commutation

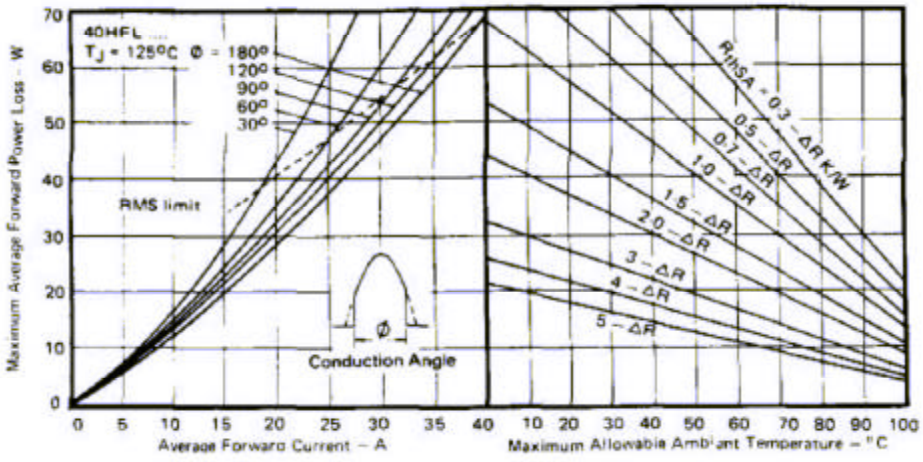
$-dI_F/dt$ = Rate of fall of forward current

$I_{RM(REC)}$ = Peak reverse recovery current

t_{rr} = Reverse recovery time

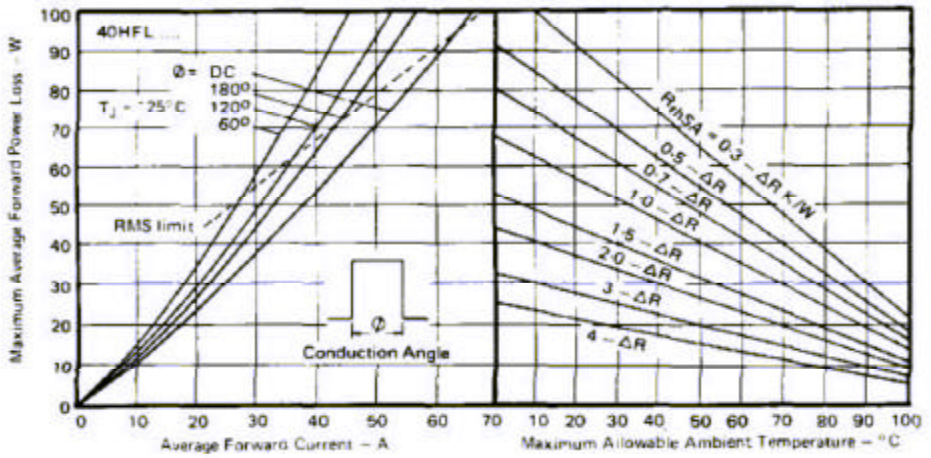
Q_{RR} = Reverse recovered charge

Fig. 1 — Reverse Recovery Time Test Waveform



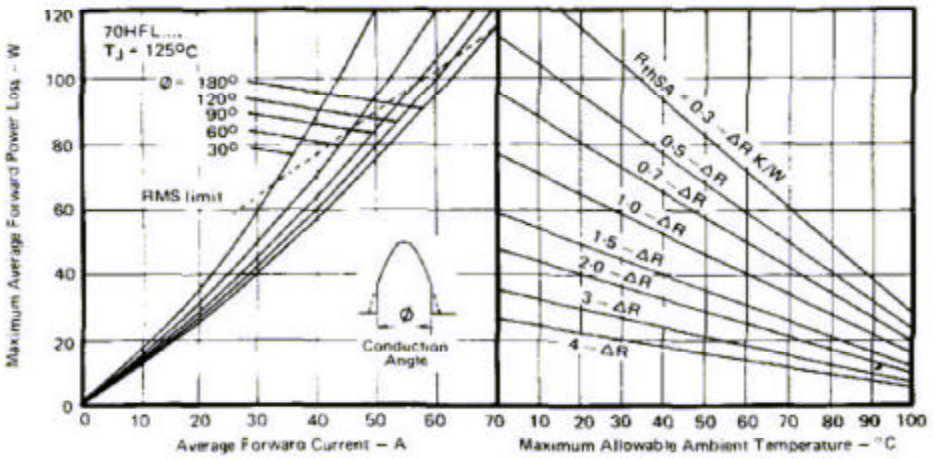
Conduction angle – Ø	ΔR K/W
180°	0.14
120°	0.15
90°	0.20
60°	0.31
30°	0.53

Fig. 2 – Current Rating Nomogram (Sinusoidal Waveforms), 40HFL Series



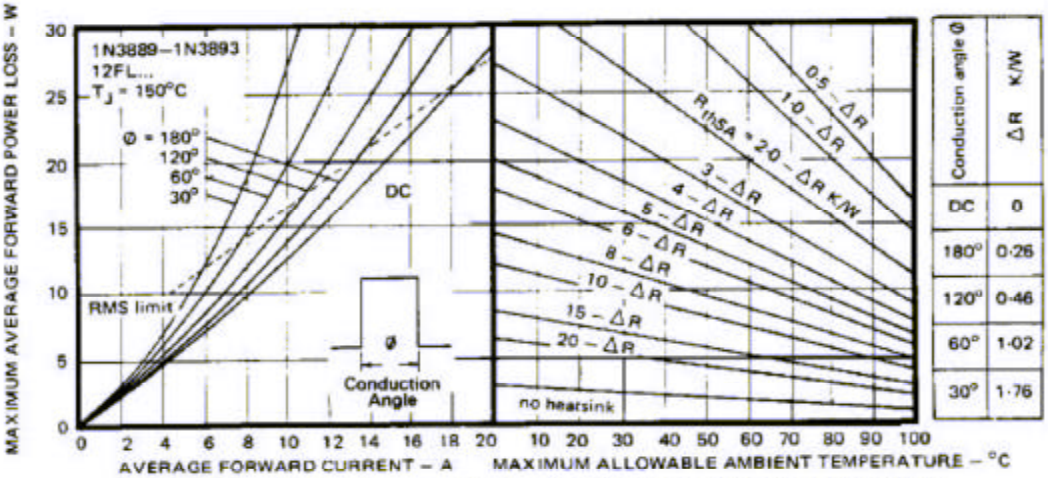
Conduction angle – Ø	ΔR K/W
DC	0
180°	0.08
120°	0.14
60°	0.30

Fig. 3 – Current Rating Nomogram (Rectangular Waveforms), 40HFL Series



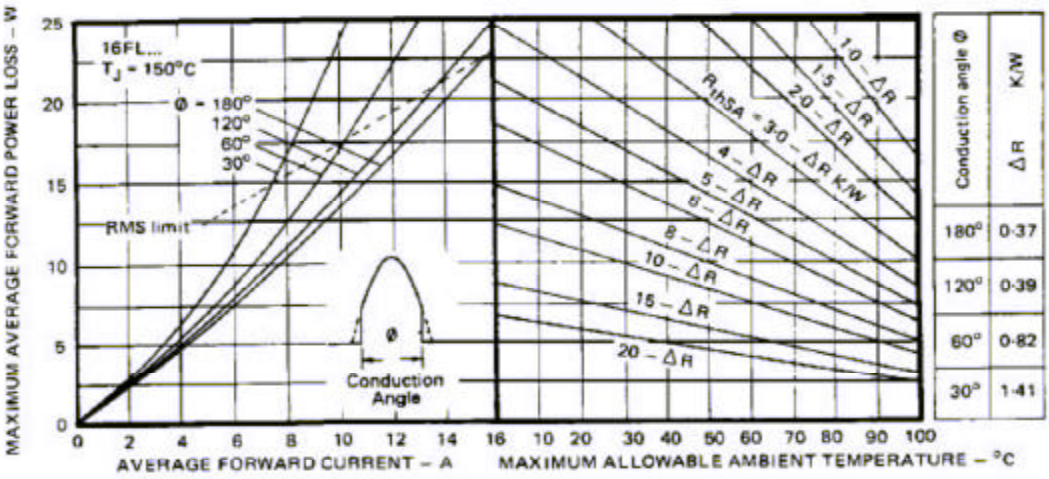
Conduction angle – Ø	ΔR K/W
180°	0.08
120°	0.09
90°	0.12
60°	0.18
30°	0.32

Fig. 4 – Current Rating Nomogram (Sinusoidal Waveforms), 70HFL Series



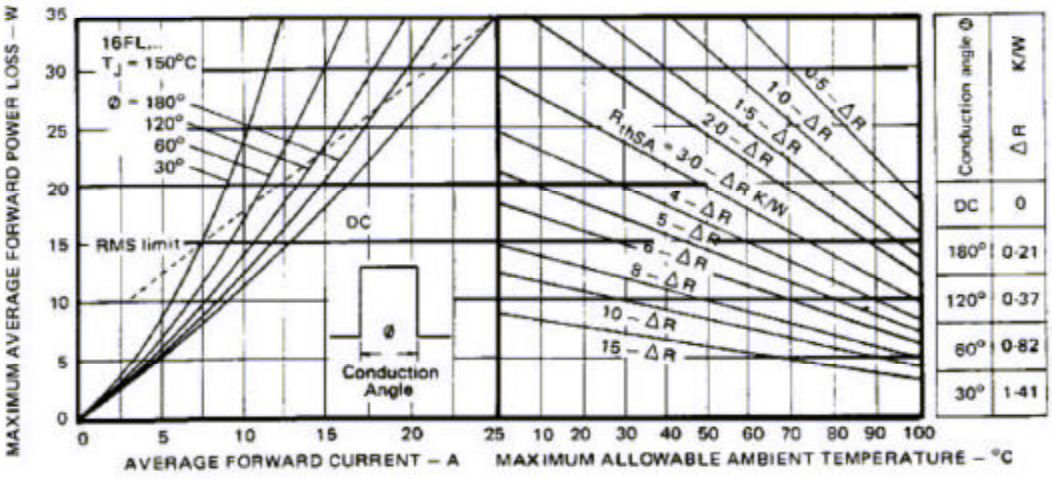
Conduction angle Ø	ΔR K/W
DC	0
180°	0·26
120°	0·46
60°	1·02
30°	1·76

Fig. 8 – Current Rating Nomogram (Rectangular Waveforms), 1N3889 and 12FL Series



Conduction angle Ø	ΔR K/W
180°	0·37
120°	0·39
60°	0·82
30°	1·41

Fig. 9 – Current Rating Nomogram (Sinusoidal Waveforms), 16FL Series



Conduction angle Ø	ΔR K/W
DC	0
180°	0·21
120°	0·37
60°	0·82
30°	1·41

Fig. 10 – Current Rating Nomogram (Rectangular Waveforms), 16FL Series

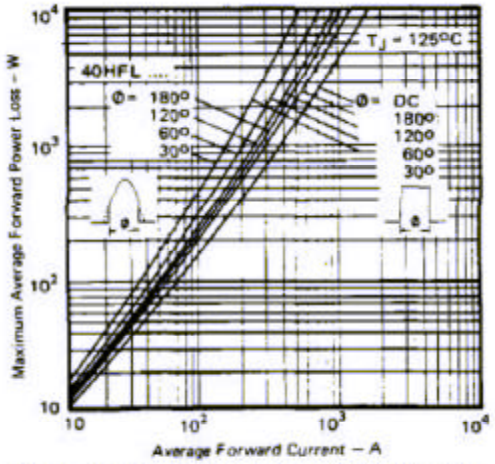


Fig. 8 – Maximum High Level Forward Power Loss Vs. Average Forward Current, 40HFL Series

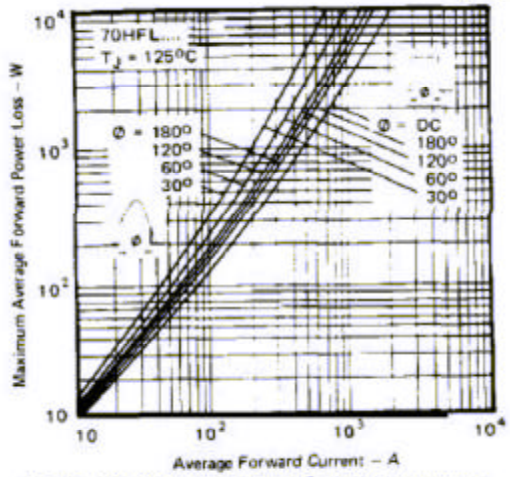


Fig. 9 – Maximum High Level Forward Power Loss Vs. Average Forward Current, 70HFL Series

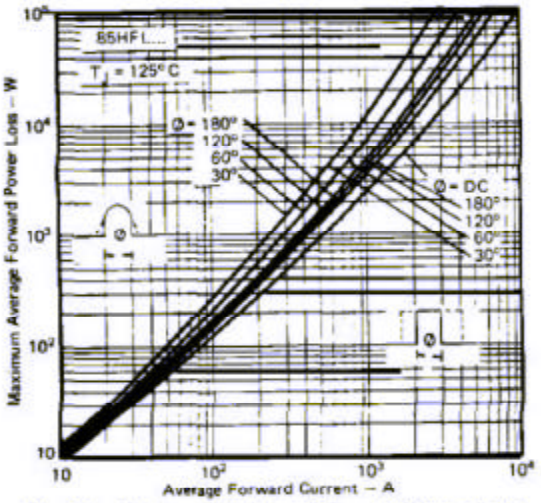


Fig. 10 – Maximum High Level Forward Power Loss Vs. Average Forward Current, 85HFL Series

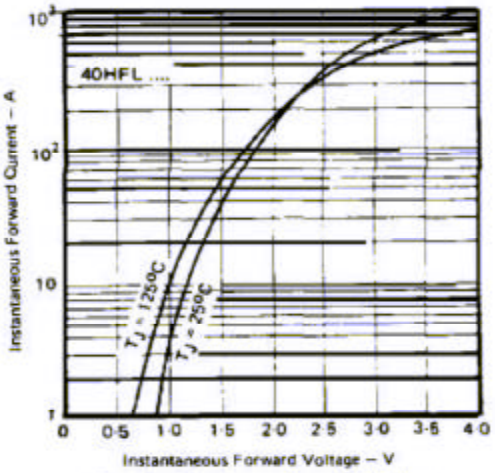


Fig. 11 – Maximum Forward Voltage Vs. Forward Current, 40HFL Series

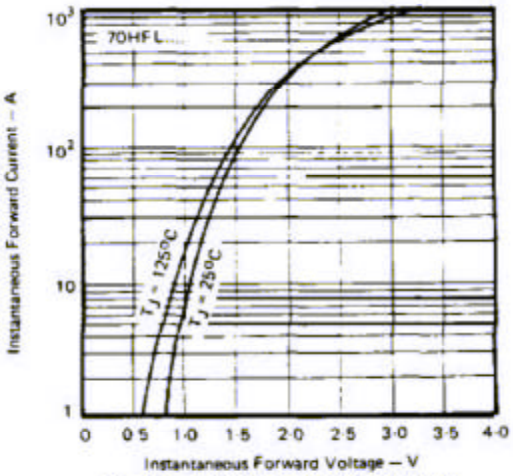


Fig. 12 – Maximum Forward Voltage Vs. Forward Current, 70HFL Series

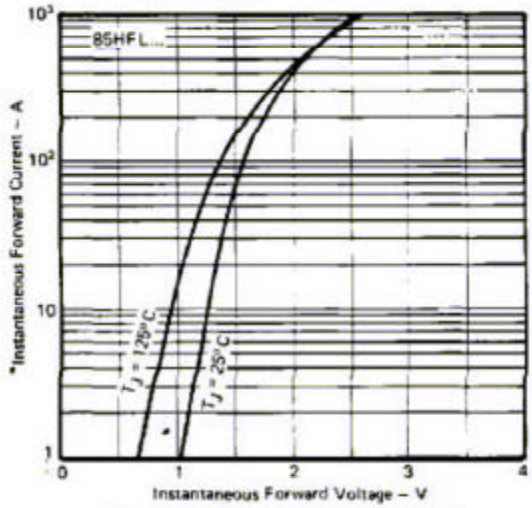


Fig. 13 – Maximum Forward Voltage Vs. Forward Current, 85HFL Series

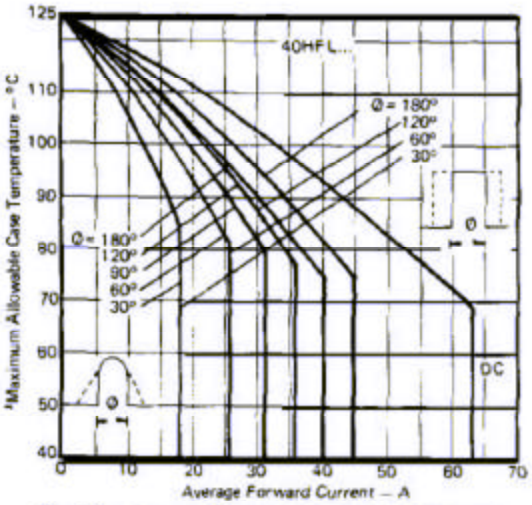


Fig. 14 – Average Forward Current Vs. Maximum Allowable Case Temperature, 40HFL Series

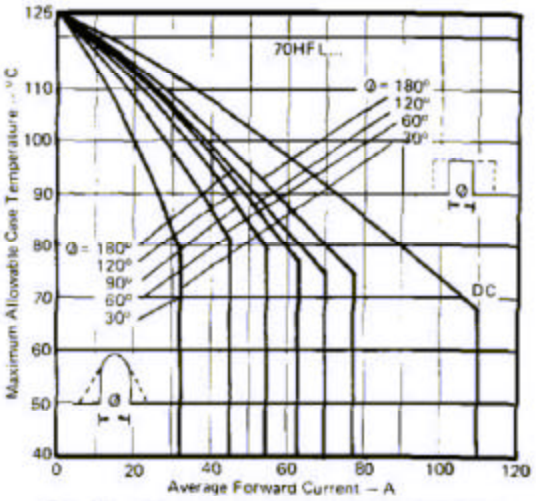


Fig. 15 – Average Forward Current Vs. Maximum Allowable Case Temperature, 70HFL Series

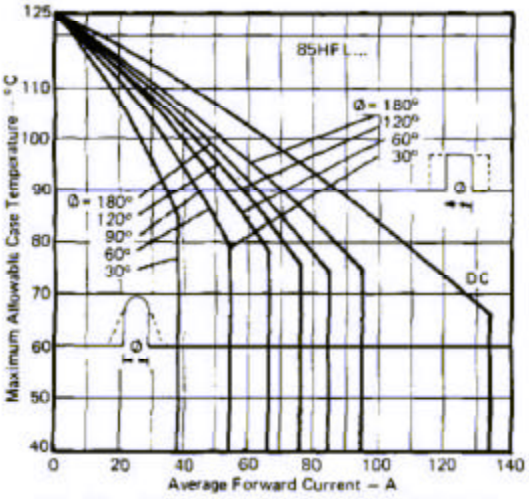


Fig. 16 – Average Forward Current Vs. Maximum Allowable Case Temperature, 85HFL Series

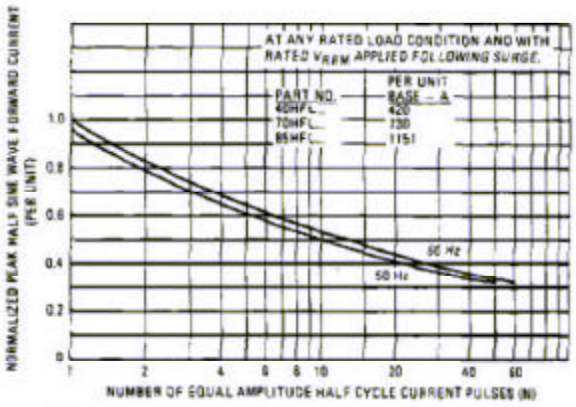


Fig. 17 – Maximum Non-Repetitive Surge Current Vs. Number of Current Pulses, All Series

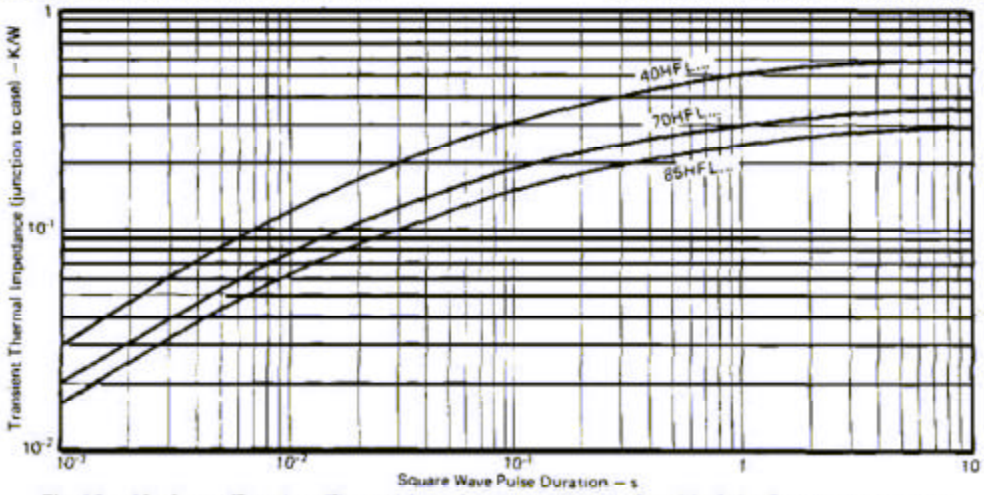


Fig. 18 – Maximum Transient Thermal Impedance, Junction-to-Case Vs. Pulse Duration, All Series

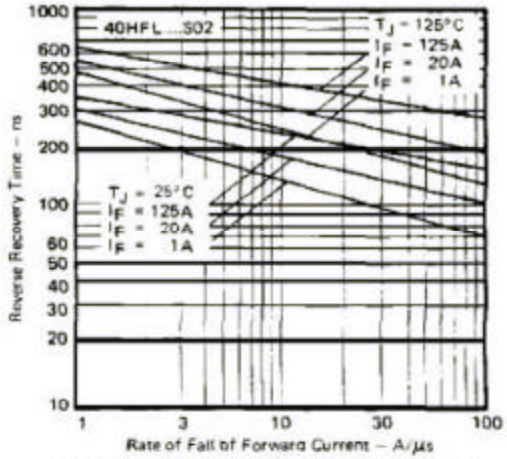


Fig. 19 – Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 40HFL__S02 Series

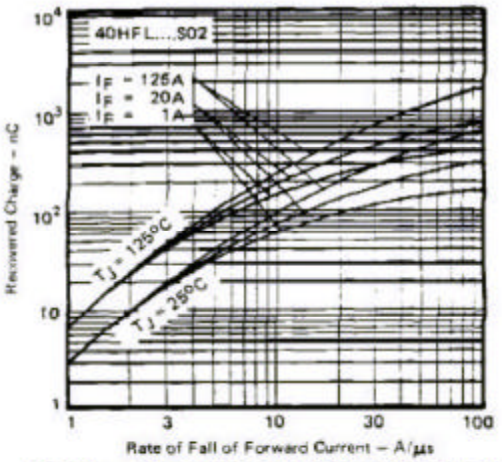


Fig. 20 – Typical Recovered Charge Vs. Rate of Fall of Forward Current, 40HFL__S02 Series

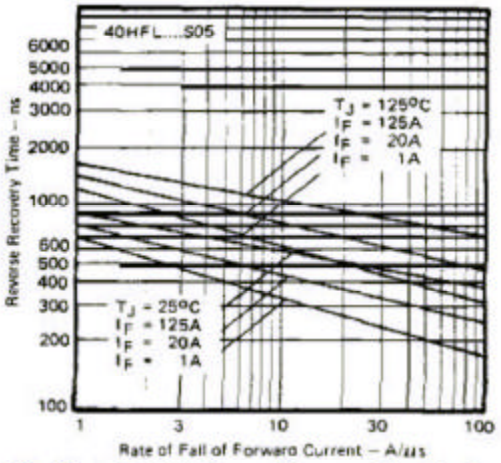


Fig. 21 – Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 40HFL__S05 Series

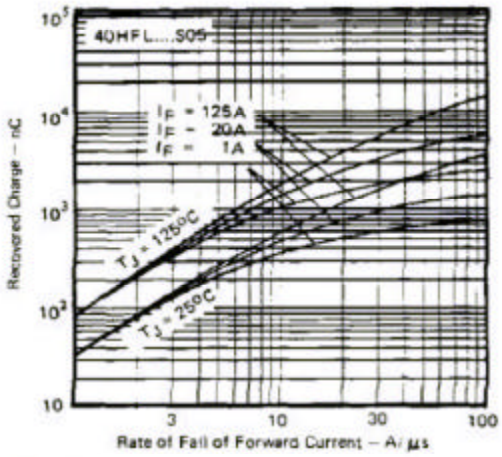


Fig. 22 – Typical Recovered Charge Vs. Rate of Fall of Forward Current, 40HFL__S05 Series

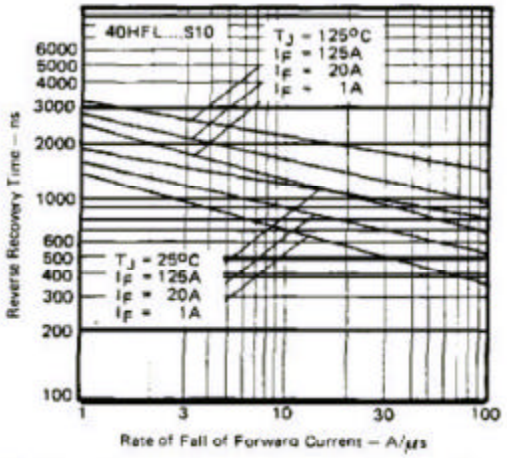


Fig. 23 – Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 40HFL__S10 Series

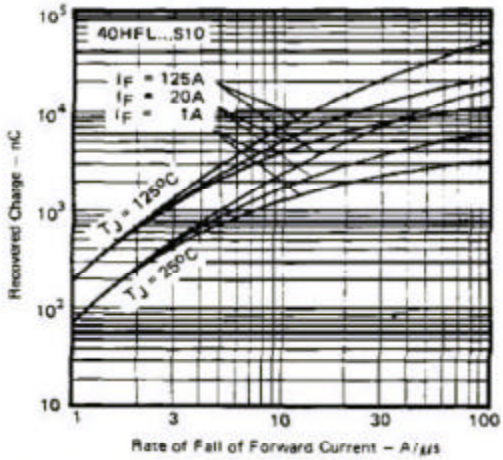


Fig. 24 – Typical Recovered Charge Vs. Rate of Fall of Forward Current, 40HFL__S10 Series

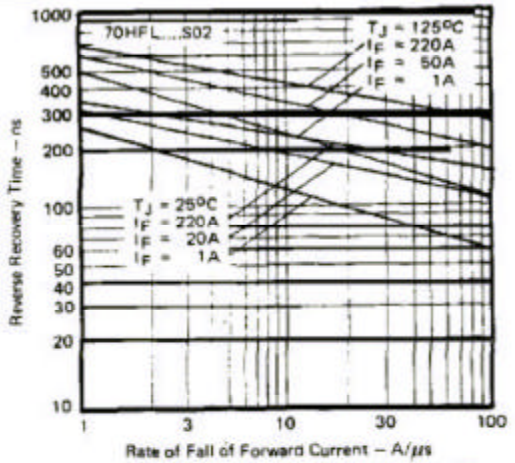


Fig. 25 – Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 70HFL__S02 Series

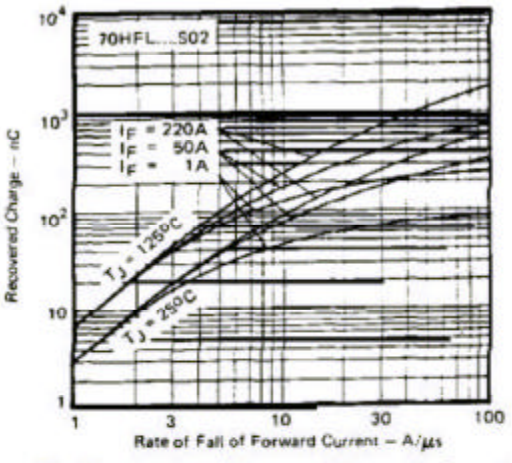


Fig. 26 – Typical Recovered Charge Vs. Rate of Fall of Forward Current, 70HFL__S02 Series

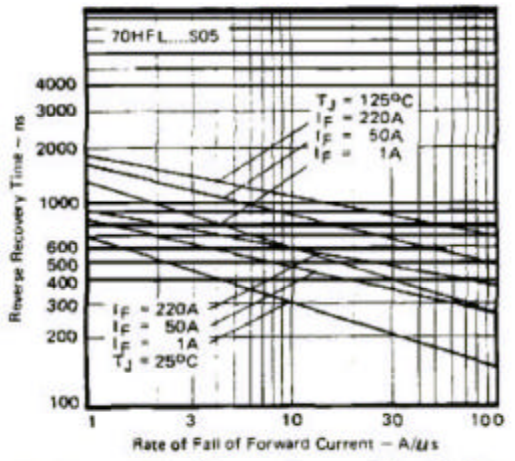


Fig. 27 – Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 70HFL__S05 Series

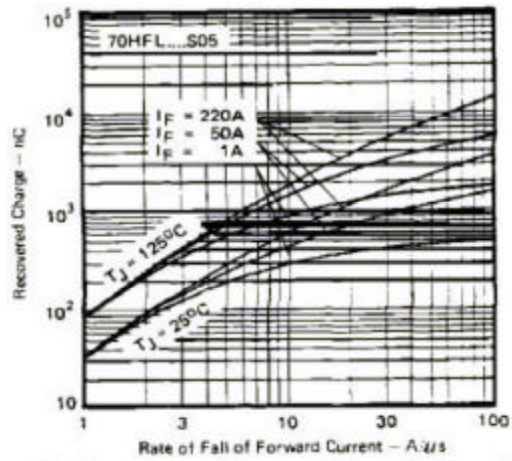


Fig. 28 – Typical Recovered Charge Vs. Rate of Fall of Forward Current, 70HFL__S05 Series

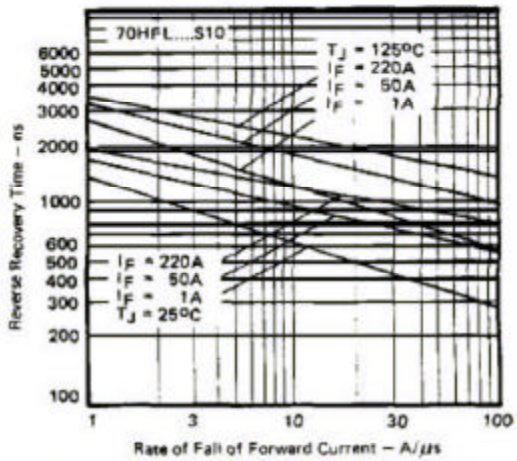


Fig. 29 – Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 70HFL__S10 Series

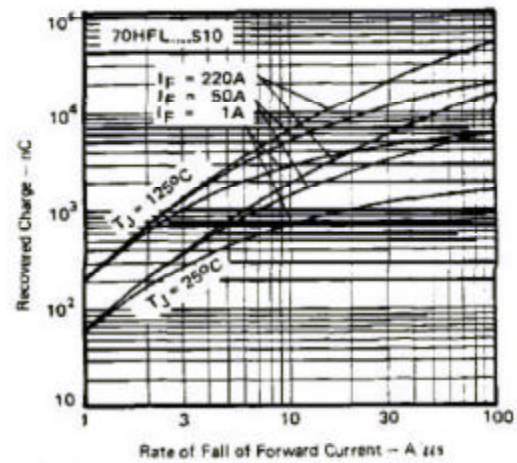


Fig. 30 – Typical Recovered Charge Vs. Rate of Fall of Forward Current, 70HFL__S10 Series

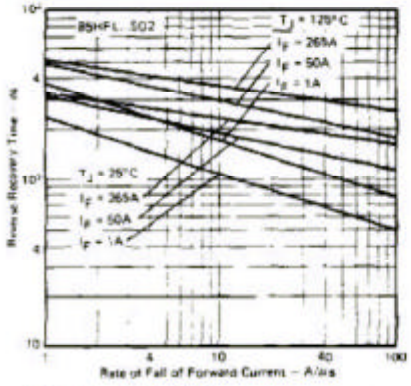


Fig. 31 – Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 85HFL__S02 Series

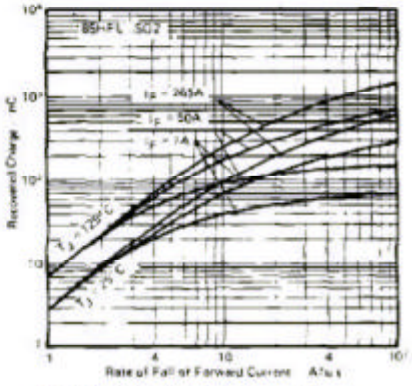


Fig. 32 – Typical Recovered Charge Vs. Rate of Fall of Forward Current, 85HFL__S02 Series

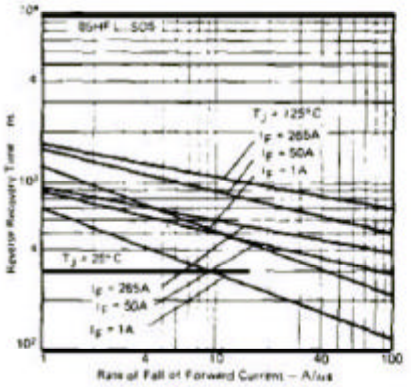


Fig. 33 – Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 85HFL__S05 Series

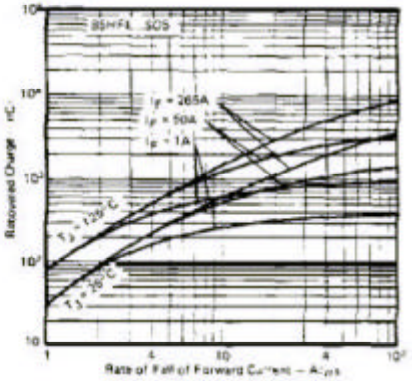


Fig. 34 – Typical Recovered Charge Vs. Rate of Fall of Forward Current, 85HFL__S05 Series

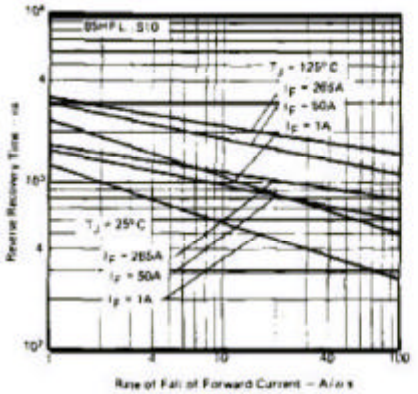


Fig. 35 – Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 85HFL__S10 Series

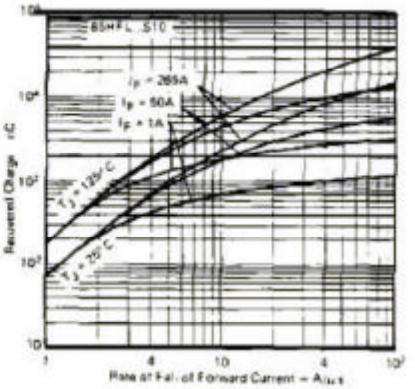


Fig. 36– Typical Recovered Charge Vs. Rate of Fall of Forward Current, 85HFL__S10 Series